



Pondicherry University
Centre for Nanoscience and Technology

Advertisement

Recruitment of Project Fellow in the DST-SERB, India Funded Research Project at the Centre for Nanoscience and Technology, Pondicherry University.

Application on plain paper is invited from eligible candidates with detailed bio-data, E-mail ID, mobile number, supported by duly attested copies of certificates and a self-addressed Rs. 5/ stamped envelope may be forwarded to the following address for a temporary research position in a **DST-India** supported Research Project. Short listed applicants will be invited for interview at Pondicherry University. **No TA/DA is admissible for attending the interview.**

1. Title of the Project: **“Deposition of High-k Dielectric Layers as MOS structures and Characterization of their Electrical Properties for Memory Applications”**
2. Duration of the project : 3 Years (Initially for One year and extendable up to Three Years)
3. Position available : **Project Fellow (Only One Position)**
4. Stipend and Qualification:
Fellowship: As per DST-India guidelines: 12,000/- per month or 16,000/- per month based on qualifications (Please refer to DST website for complete details).
Qualifications:
(a) M.Sc. in Physics/Chemistry/Materials Science/Nanoscience and Technology
(b) M.Tech. Materials Science/Nanoscience and Technology
(Other terms remain the same as in the DST guidelines)

Desirable: 1. CSIR, NET, GATE qualifications
2. Research experience with Dielectric/Optical Materials/microelectronic devices.
5. Last Date for application : **23-12-2013 (5.30 PM)**
6. Address for sending the application: **Dr. P. THANGADURAI**
Assistant Professor
Centre for Nanoscience and Technology
Madanjeet School of Green Energy Technologies
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Issuing Date: 05-12-2013

Issuing Authority: Dr. P. Thangadurai, Assistant Professor, Centre for Nanoscience and Technology, Pondicherry University